

### STP60NF06

# N-channel 60V - $0.014\Omega$ - 60A TO-220 STripFET II<sup>TM</sup> Power MOSFET

#### **General features**

Туре	V <sub>DSS</sub> R <sub>DS(on)</sub>		V <sub>DSS</sub> R <sub>DS(on)</sub>		I <sub>D</sub>
STP60NF06	60V	<0.016Ω	60A		

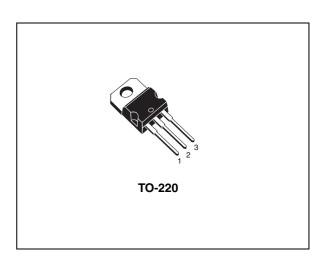
- Exceptional dv/dt capability
- 100% avalanche tested
- Application oriented characterization

#### **Description**

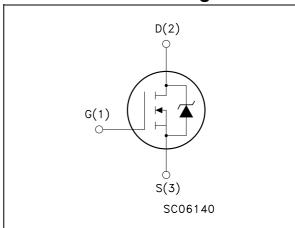
This Power MOSFET series realized with STMicroelectronics unique STripFET process has specifically been designed to minimize input capacitance and gate charge. It is therefore suitable as primary switch in advanced highefficiency isolated DC-DC converters for Telecom and Computer application. It is also intended for any application with low gate charge drive requirements.

#### **Applications**

■ Switching application



#### Internal schematic diagram



#### Order code

Part number	Marking	Package	Packaging
STP60NF06	P60NF06	TO-220	Tube

Contents STP60NF06

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STP60NF06 Electrical ratings

# 1 Electrical ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V <sub>DS</sub>	Drain-source voltage (V <sub>GS</sub> = 0)	60	V
V <sub>GS</sub>	Gate- source voltage	±20	V
I <sub>D</sub>	Drain current (continuos) at T <sub>C</sub> = 25°C	60	Α
I <sub>D</sub>	Drain current (continuos) at T <sub>C</sub> = 100°C	42	Α
I <sub>DM</sub> <sup>(1)</sup>	Drain current (pulsed)	240	Α
P <sub>TOT</sub>	Total dissipation at T <sub>C</sub> = 25°C	110	
	Derating factor	0.74	
dv/dt (2)	Peak diode recovery voltage slope 7.5		V/ns
T <sub>stg</sub>	Storage temperature	- 55 to 175	
T <sub>j</sub>	Max. operating junction temperature	- 55 to 175	°C

<sup>1.</sup> Pulse width limited by safe operating area

Table 2. Thermal data

Symbol	Parameter	Value	Unit
R <sub>thj-case</sub>	Thermal resistance junction-case max	1.36	°C/W
R <sub>thj-a</sub>	Thermal resistance junction-ambient max	62.5	°C/W
T <sub>I</sub>	Maximum lead temperature for soldering purpose	300	°C

Table 3. Avalanche characteristics

Symbol	Parameter	Value	Unit
I <sub>AR</sub>	Avalanche current, repetitive or not-repetitive (pulse width limited by Tj Max)	30	А
E <sub>AS</sub>	Single pulse avalanche energy (starting Tj=25°C, Id=lar, Vdd=30V)		mJ

<sup>2.</sup>  $I_{SD} \leq 60A$ , di/dt  $\leq 400 A/\mu s$ ,  $V_{DD} \leq 48V$ ,  $Tj \leq T_{jmax}$ 

Electrical characteristics STP60NF06

## 2 Electrical characteristics

( $T_{CASE}$ =25°C unless otherwise specified)

Table 4. On/off states

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
V <sub>(BR)DSS</sub>	Drain-source Breakdown voltage	$I_D = 250 \mu A, V_{GS} = 0$	60			V
	Zero gate voltage	V <sub>DS</sub> = Max rating			1	μΑ
I <sub>DSS</sub>	Drain current (V <sub>GS</sub> = 0)	V <sub>DS</sub> =Max rating, T <sub>C</sub> =125°C			10	μΑ
I <sub>GSS</sub>	Gate-body leakage current (V <sub>DS</sub> = 0)	V <sub>GS</sub> = ±20V			±100	nA
V <sub>GS(th)</sub>	Gate threshold voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2		4	٧
R <sub>DS(on)</sub>	Static drain-source on resistance	V <sub>GS</sub> = 10V, I <sub>D</sub> = 30A		0.014	0.016	Ω

Table 5. Dynamic

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
g <sub>fs</sub> <sup>(1)</sup>	Forward transconductance	V <sub>DS</sub> = 15V <sub>,</sub> I <sub>D</sub> =30A		50		S
C <sub>iss</sub>	Input capacitance			1660		pF
C <sub>oss</sub>	Output capacitance	$V_{DS} = 25V, f = 1 MHz,$		400		pF
C <sub>rss</sub>	Reverse transfer capacitance	V <sub>GS</sub> = 0		140		pF
Qg	Total gate charge	$V_{DD} = 30V, I_D = 60A,$		54	73	nC
$Q_{gs}$	Gate-source charge	$V_{DD} = 30V, I_{D} = 60A,$ $V_{GS} = 10V$		9		nC
$Q_{gd}$	Gate-drain charge	(see Figure 12)		23		nC

<sup>1.</sup> Pulsed: Pulse duration = 300 μs, duty cycle 1.5%

Table 6. Switching times

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t <sub>d(on)</sub>	Turn-on delay time Rise time	$V_{DD} = 30$ V, $I_D = 30$ A $R_G = 4.7\Omega V_{GS} = 10$ V (see Figure 11)		15 65		ns ns
t <sub>d(off)</sub>	Turn-off-delay time Fall time	$V_{DD}$ = 30V, $I_D$ = 30A, $R_G$ = 4.7 $\Omega$ , $V_{GS}$ =10V (see Figure 11)		45 20		ns ns

Table 7. Source drain diode

Symbol	Parameter	Test conditions	Min	Тур.	Max	Unit
I <sub>SD</sub>	Source-drain current				60	Α
I <sub>SDM</sub> <sup>(1)</sup>	Source-drain current (pulsed)				240	Α
V <sub>SD</sub> <sup>(2)</sup>	Forward on voltage	$I_{SD} = 60A, V_{GS} = 0$			1.3	V
t <sub>rr</sub>	Reverse recovery time	$I_{SD} = 60A, V_{DD} = 30V$		70		ns
$Q_{rr}$	Reverse recovery charge	di/dt = 100A/μs, Tj = 150°C		185		nC
I <sub>RRM</sub>	Reverse recovery current	(see Figure 13)		5		Α

<sup>1.</sup> Pulse width limited by safe operating area.

<sup>2.</sup> Pulsed: Pulse duration = 300  $\mu$ s, duty cycle 1.5%

Electrical characteristics STP60NF06

### 2.1 Electrical characteristics (curves)

Figure 1. Safe operating area

Figure 2. Thermal impedance

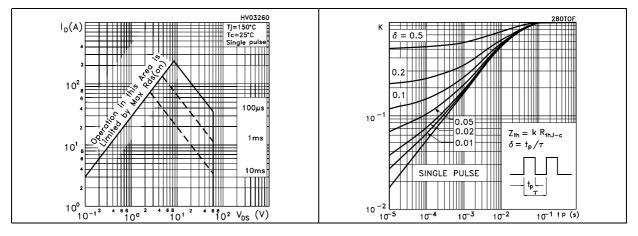


Figure 3. Output characteristics

Figure 4. Transfer characteristics

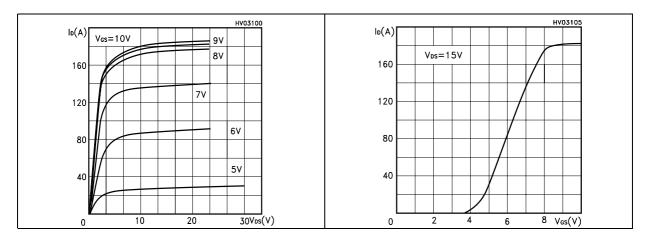
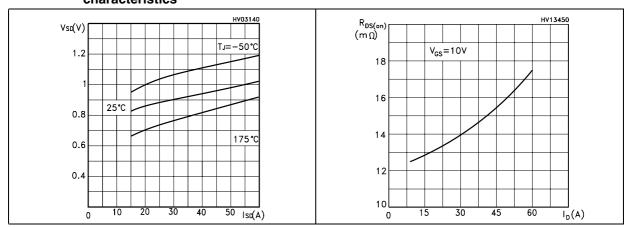


Figure 5. Source-drain diode forward characteristics

Figure 6. Static drain-source on resistance



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Figure 7. Gate charge vs gate-source voltage Figure 8. Capacitance variations

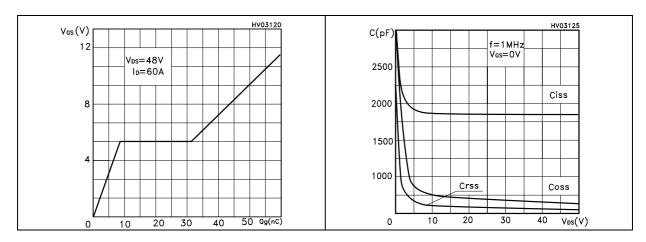
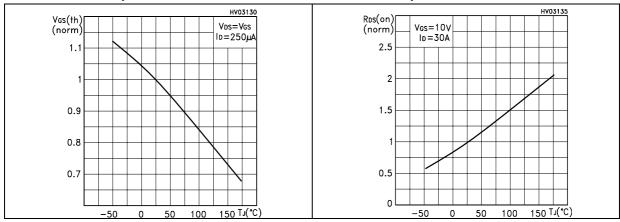


Figure 9. Normalized gate threshold voltage Figure 10. Normalized on resistance vs vs temperature temperature



Test circuit STP60NF06

### 3 Test circuit

Figure 11. Switching times test circuit for resistive load

Figure 12. Gate charge test circuit

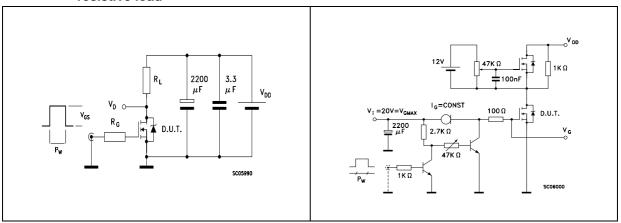


Figure 13. Test circuit for inductive load switching and diode recovery times

Figure 14. Unclamped Inductive load test circuit

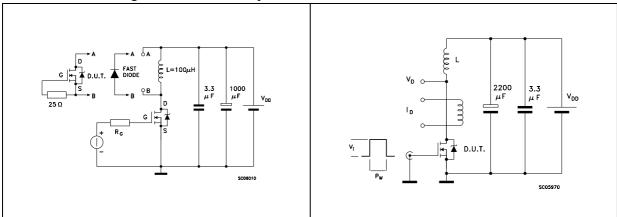
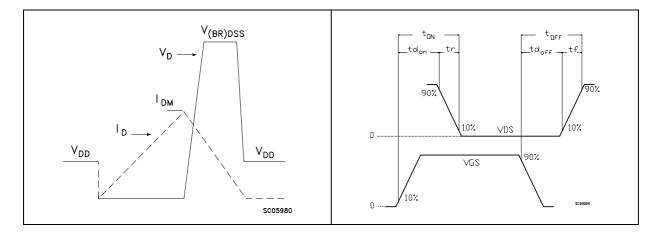


Figure 15. Unclamped inductive waveform

Figure 16. Switching time waveform



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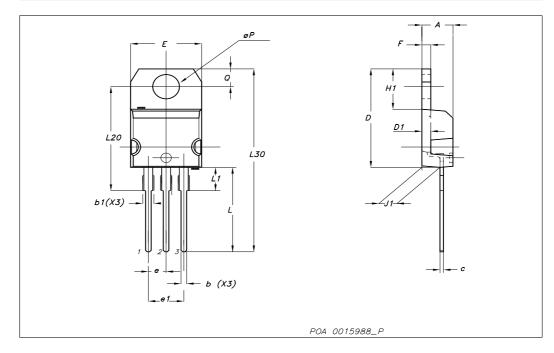
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## 4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: <a href="https://www.st.com">www.st.com</a>

#### TO-220 mechanical data

Dim		mm			inch	
DIM	Min	Тур	Max	Min	Тур	Max
A	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
С	0.49		0.70	0.019		0.027
D	15.25		15.75	0.6		0.62
D1		1.27			0.050	
E	10		10.40	0.393		0.409
е	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.051
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90			1.137	
θР	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



STP60NF06 Revision history

# 5 Revision history

Table 8. Revision history

Date	Revision	vision Changes	
09-Sep-2004	3	Complete version	
17-Aug-2006	4	The document has been reformatted	
04-Oct-2006	5	Changes in <i>Dynamic</i>	
02-Mar-2007	6	Safe operating area has been updated	

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